

FORM PTO 1449 (modified)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICELIST OF REFERENCES CITED BY APPLICANT(S)
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APPLICANT

SEISHIRO YOSHIOKA ET AL.

FILING DATE

June 2, 2000

GROUP 1722

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U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
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KJR	5285129	02/1994	Takeda, et al.	313	309	
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KJR	5559342	9/96	Tsukamoto et al.	257	10	
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K/K		"Energy Distribution of Emitted Electrons from Electroformed MIM Structures: The Carbon Island Model," M. Bischoff, H. Pagnia and J. Trinkl, Int. J. Electronics, Vol 73, No 5, pp. 1009-1010 (1992) <i>no month</i>
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EXAMINER	KENNETH J. RAMSEY PRIMARY EXAMINER
	DATE CONSIDERED 4/23/01

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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